

Standard Rectifier

 V_{RRM} 1200 V =

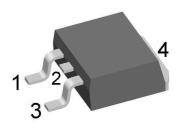
30 A

 V_{F} 1.25 V

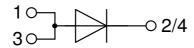
Single Diode

Part number

DSI30-12AS



Backside: cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

Applications:

- Diode for main rectification
- For single and three phase bridge configurations

Package: TO-263 (D2Pak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Terms _Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact the sales office, which is responsible for you.

Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact the sales office, which is responsible for you.

Should you intend to use the product in aviation, in health or live endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

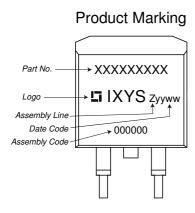


| Rectifier | | | | | Ratings | | |
|-------------------|-----------------------------------|--|--------------------------|------|---------|------|------------------|
| Symbol | Definition | Conditions | | min. | typ. | max. | Unit |
| V _{RSM} | max. non-repetitive reverse bloc | cking voltage | $T_{VJ} = 25^{\circ}C$ | | | 1300 | V |
| V _{RRM} | max. repetitive reverse blocking | voltage | $T_{VJ} = 25^{\circ}C$ | | | 1200 | V |
| I _R | reverse current | V _R = 1200 V | $T_{VJ} = 25^{\circ}C$ | | | 40 | μΑ |
| | | $V_R = 1200 \text{ V}$ | $T_{VJ} = 150$ °C | | | 1.5 | mΑ |
| V _F | forward voltage drop | I _F = 30 A | $T_{VJ} = 25^{\circ}C$ | | | 1.29 | V |
| | | $I_F = 60 \text{ A}$ | | | | 1.60 | ٧ |
| | | I _F = 30 A | T _{VJ} = 150 °C | | | 1.25 | ٧ |
| | | $I_F = 60 \text{ A}$ | | | | 1.66 | ٧ |
| I FAV | average forward current | T _C = 130°C | $T_{VJ} = 175$ °C | | | 30 | Α |
| | | rectangular d = 0.5 | | | | | i |
| V _{F0} | threshold voltage | | T _{vJ} = 175°C | | | 0.82 | ٧ |
| r _F | slope resistance \(\) for power | loss calculation only | | | | 14.1 | mΩ |
| R _{thJC} | thermal resistance junction to ca | ase | | | | 0.9 | K/W |
| R _{thCH} | thermal resistance case to heats | sink | | | 0.25 | | K/W |
| P _{tot} | total power dissipation | | $T_{C} = 25^{\circ}C$ | | | 160 | W |
| I _{FSM} | max. forward surge current | t = 10 ms; (50 Hz), sine | $T_{VJ} = 45^{\circ}C$ | | | 300 | Α |
| | | t = 8,3 ms; (60 Hz), sine | $V_R = 0 V$ | | | 325 | Α |
| | | t = 10 ms; (50 Hz), sine | T _{VJ} = 150°C | | | 255 | Α |
| | | t = 8,3 ms; (60 Hz), sine | $V_R = 0 V$ | | | 275 | Α |
| I²t | value for fusing | t = 10 ms; (50 Hz), sine | $T_{VJ} = 45^{\circ}C$ | | | 450 | A ² s |
| | | t = 8,3 ms; (60 Hz), sine | $V_R = 0 V$ | | | 440 | A²s |
| | | t = 10 ms; (50 Hz), sine | $T_{VJ} = 150$ °C | | | 325 | A ² s |
| | | t = 8.3 ms; (60 Hz), sine | $V_R = 0 V$ | | | 315 | A²s |
| CJ | junction capacitance | $V_{R} = 400 \text{ V}; f = 1 \text{ MHz}$ | $T_{VJ} = 25^{\circ}C$ | | 10 | | pF |



| Package TO-263 (D2Pak) | | | | Ratings | | | |
|------------------------|------------------------------|-----------------|------|---------|------|------|--|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit | |
| IRMS | RMS current | per terminal 1) | | | 35 | Α | |
| T _{VJ} | virtual junction temperature | | -40 | | 175 | °C | |
| T _{op} | operation temperature | | -40 | | 150 | °C | |
| T _{stg} | storage temperature | | -40 | | 150 | °C | |
| Weight | | | | 2 | | g | |
| F _c | mounting force with clip | | 20 | | 60 | N | |

¹⁾ I_{nusc} is typically limited by the pin-to-chip resistance (1); or by the current capability of the chip (2). In case of (1) and a product with multiple pins for one chip-potential, the current capability can be increased by connecting the pins as one contact.



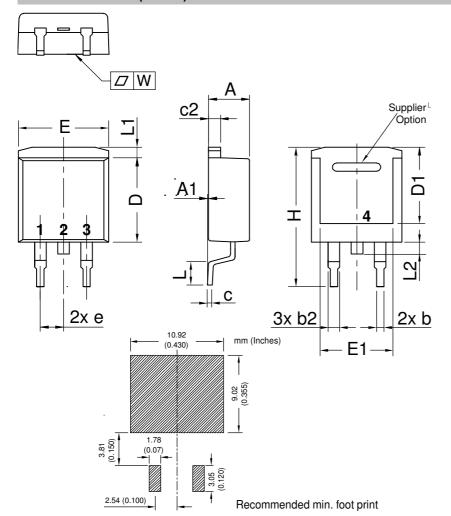
| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|-------------|-----------------|--------------------|---------------|----------|----------|
| Standard | DSI30-12AS | DSI30-12AS | Tape & Reel | 800 | 507511 |
| Alternative | DSI30-12AS-TUB | DSI30-12AS | Tube | 50 | 470988 |

| Similar Part | Package | Voltage class |
|--------------|----------------------|---------------|
| DSI30-12A | TO-220AC (2) | 1200 |
| DSI30-12AC | ISOPLUS220AC (2) | 1200 |
| DSI30-16AS | TO-263AB (D2Pak) (2) | 1600 |
| DSI30-16A | TO-220AC (2) | 1600 |
| DSI30-08AS | TO-263AB (D2Pak) (2) | 800 |
| DSI30-08A | TO-220AC (2) | 800 |
| DSI30-08AC | ISOPLUS220AC (2) | 800 |

| Equivalent Circuits for Simulation | | | * on die level | $T_{VJ} = 175 ^{\circ}\text{C}$ |
|---|--------------------|-----------|----------------|---------------------------------|
| $I \rightarrow V_0$ | R_0 | Rectifier | | |
| V _{0 max} | threshold voltage | 0.82 | | V |
| $R_{0 \text{ max}}$ | slope resistance * | 11 | | $m\Omega$ |

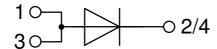


Outlines TO-263 (D2Pak)



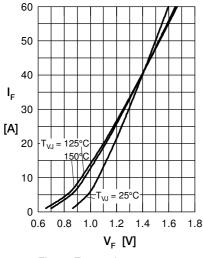
| | Millimeter | | Inches | | |
|------|--------------|-------|----------------|-------|--|
| Dim. | min | max | min | max | |
| Α | 4.06 | 4.83 | 0.160 | 0.190 | |
| A1 | typ. | 0.10 | typ. 0.004 | | |
| A2 | 2. | | | 0.095 | |
| b | 0.51 | 0.99 | 0.020 | 0.039 | |
| b2 | 1.14 | 1.40 | 0.045 | 0.055 | |
| С | 0.40 | 0.74 | 0.016 | 0.029 | |
| c2 | 1.14 | 1.40 | 0.045 | 0.055 | |
| D | 8.38 | 9.40 | 0.330 | 0.370 | |
| D1 | 8.00 | 8.89 | 0.315 | 0.350 | |
| D2 | 2 | .5 | 0.098 | | |
| Е | 9.65 | 10.41 | 0.380 | 0.410 | |
| E1 | 6.22 | 8.50 | 0.245 | 0.335 | |
| е | 2,54 | BSC | 0,100 | BSC | |
| e1 | 4.28 | | 0.169 | | |
| Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| L | 1.78 | 2.79 | 0.070 | 0.110 | |
| L1 | 1.02 | 1.68 | 0.040 | 0.066 | |
| W | typ. 0.02 | 0.040 | typ. 0.0008 | 0.002 | |

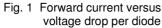
All dimensions conform with and/or within JEDEC standard.





Rectifier





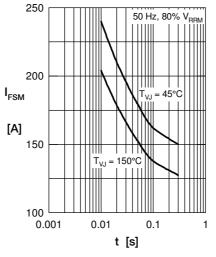


Fig. 2 Surge overload current

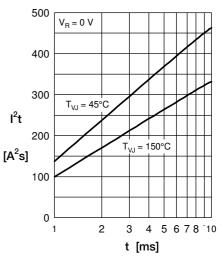


Fig. 3 I²t versus time per diode

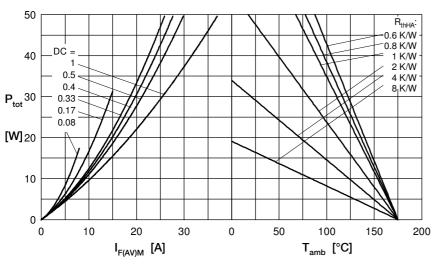


Fig. 4 Power dissipation vs. direct output current and ambient temperature

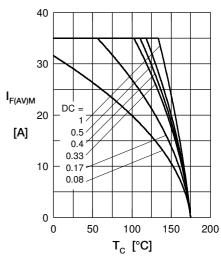


Fig. 5 Max. forward current vs. case temperature

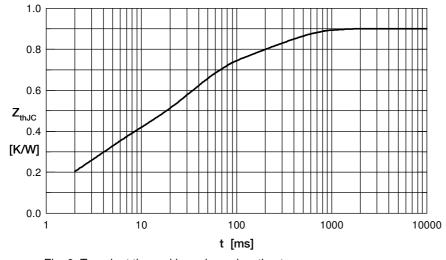


Fig. 6 Transient thermal impedance junction to case

Constants for Z_{thJC} calculation:

| i | $\boldsymbol{R}_{thi} \; (K/W)$ | t _i (s) |
|---|---------------------------------|--------------------|
| 1 | 0.03 | 0.0004 |
| 2 | 80.0 | 0.002 |
| 3 | 0.2 | 0.003 |
| 4 | 0.39 | 0.03 |
| 5 | 0.2 | 0.29 |

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